Edoardo Charbon

List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

38 58 4,511 203 h-index g-index citations papers 6.09 5,830 225 4.3 avg, IF L-index ext. citations ext. papers

#	Paper	IF	Citations
203	Light detection and ranging with entangled photons Optics Express, 2022, 30, 3675-3683	3.3	2
202	2.5 Hz sample rate time-domain near-infrared optical tomography based on SPAD-camera image tissue hemodynamics <i>Biomedical Optics Express</i> , 2022 , 13, 133-146	3.5	0
201	IEEE Open Journal of the Solid-State Circuits Society Special Section on Imagers for 3D Vision. <i>IEEE Open Journal of the Solid-State Circuits Society</i> , 2022 , 2, 1-2		
200	On Analog Silicon Photomultipliers in Standard 55-nm BCD Technology for LiDAR Applications. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2022 , 1-1	3.8	1
199	Guard-Ring-Free InGaAs/InP Single-Photon Avalanche Diode Based on a Novel Zn-diffusion Technique. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2022 , 1-1	3.8	O
198	Back-gate effects on DC performance and carrier transport in 22 nm FDSOI technology down to cryogenic temperatures. <i>Solid-State Electronics</i> , 2022 , 193, 108296	1.7	2
197	A cryo-CMOS chip that integrates silicon quantum dots and multiplexed dispersive readout electronics. <i>Nature Electronics</i> , 2022 , 5, 53-59	28.4	2
196	Toward Super Temporal Resolution by Suppression of Mixing Effects of Electrons. <i>IEEE Transactions on Electron Devices</i> , 2022 , 1-7	2.9	
195	A 1 W radiation-hard front-end in a 0.18 th CMOS process for the MALTA2 monolithic sensor. <i>IEEE Transactions on Nuclear Science</i> , 2022 , 1-1	1.7	O
194	A 500 x 500 Dual-Gate SPAD Imager With 100% Temporal Aperture and 1 ns Minimum Gate Length for FLIM and Phasor Imaging Applications. <i>IEEE Transactions on Electron Devices</i> , 2022 , 1-8	2.9	1
193	A Cryo-CMOS Wideband Quadrature Receiver With Frequency Synthesizer for Scalable Multiplexed Readout of Silicon Spin Qubits. <i>IEEE Journal of Solid-State Circuits</i> , 2022 , 1-1	5.5	
192	Pixel super-resolution with spatially entangled photons. <i>Nature Communications</i> , 2022 , 13,	17.4	4
191	A massively scalable Time-to-Digital Converter with a PLL-free calibration system in a commercial 130 nm process. <i>Journal of Instrumentation</i> , 2021 , 16, P11023	1	1
190	Theoretical minimum uncertainty of single-molecule localizations using a single-photon avalanche diode array. <i>Optics Express</i> , 2021 , 29, 39920-39929	3.3	1
189	Cryogenic Characterization of 16 nm FinFET Technology for Quantum Computing 2021,		1
188	A Pixel Design of a Branching Ultra-Highspeed Image Sensor. <i>Sensors</i> , 2021 , 21,	3.8	1
187	Full-field quantum imaging with a single-photon avalanche diode camera. <i>Physical Review A</i> , 2021 , 103,	2.6	8

186	CMOS-based cryogenic control of silicon quantum circuits. <i>Nature</i> , 2021 , 593, 205-210	50.4	29	
185	A Scaling Law for SPAD Pixel Miniaturization. <i>Sensors</i> , 2021 , 21,	3.8	3	
184	A Cryogenic Broadband Sub-1-dB NF CMOS Low Noise Amplifier for Quantum Applications. <i>IEEE Journal of Solid-State Circuits</i> , 2021 , 56, 2040-2053	5.5	3	
183	Cryogenic CMOS Circuits and Systems: Challenges and Opportunities in Designing the Electronic Interface for Quantum Processors. <i>IEEE Microwave Magazine</i> , 2021 , 22, 60-78	1.2	5	
182	Engineering Breakdown Probability Profile for PDP and DCR Optimization in a SPAD Fabricated in a Standard 55nm BCD Process. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2021 , 1-1	3.8	4	
181	A Low-noise CMOS SPAD Pixel with 12.1 ps SPTR and 3 ns Dead Time. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2021 , 1-1	3.8	7	
180	Superluminal Motion-Assisted Four-Dimensional Light-in-Flight Imaging. <i>Physical Review X</i> , 2021 , 11,	9.1	2	
179	A Low-Jitter and Low-Spur Charge-Sampling PLL. IEEE Journal of Solid-State Circuits, 2021, 1-1	5.5	3	
178	In Phantom Validation of Time-Domain Near-Infrared Optical Tomography Pioneer for Imaging Brain Hypoxia and Hemorrhage. <i>Advances in Experimental Medicine and Biology</i> , 2021 , 1269, 341-346	3.6	2	
177	13.2 A Fully-Integrated 40-nm 5-6.5 GHz Cryo-CMOS System-on-Chip with I/Q Receiver and Frequency Synthesizer for Scalable Multiplexed Readout of Quantum Dots 2021 ,		8	
176	The Michelangelo step: removing scalloping and tapering effects in high aspect ratio through silicon vias. <i>Scientific Reports</i> , 2021 , 11, 3997	4.9	4	
175	13.3 A 6-to-8GHz 0.17mW/Qubit Cryo-CMOS Receiver for Multiple Spin Qubit Readout in 40nm CMOS Technology 2021 ,		4	
174	Light Extraction Enhancement Techniques for Inorganic Scintillators. <i>Crystals</i> , 2021 , 11, 362	2.3	2	
173	Towards Quantum 3D Imaging Devices. Applied Sciences (Switzerland), 2021, 11, 6414	2.6	2	
172	Heralded Spectroscopy Reveals Exciton-Exciton Correlations in Single Colloidal Quantum Dots. <i>Nano Letters</i> , 2021 , 21, 6756-6763	11.5	1	
171	Single-photon avalanche diode imaging sensor for subsurface fluorescence LiDAR. <i>Optica</i> , 2021 , 8, 112	6 8.6	O	
170	Blumino: The First Fully Integrated Analog SiPM With On-Chip Time Conversion. <i>IEEE Transactions on Radiation and Plasma Medical Sciences</i> , 2021 , 5, 671-678	4.2	4	
169	Probe Design Optimization for Time-Domain NIROT "Pioneer" System for Imaging the Oxygenation of the Preterm Brain. <i>Advances in Experimental Medicine and Biology</i> , 2021 , 1269, 359-363	3.6		

168	. IEEE Solid-State Circuits Magazine, 2021 , 13, 54-68	1.5	О
167	Scaling silicon-based quantum computing using CMOS technology. <i>Nature Electronics</i> , 2021 , 4, 872-884	28.4	10
166	Measurements and analysis of different front-end configurations for monolithic SiGe BiCMOS pixel detectors for HEP applications. <i>Journal of Instrumentation</i> , 2021 , 16, P12038	1	О
165	Characterization and Analysis of On-Chip Microwave Passive Components at Cryogenic Temperatures. <i>IEEE Journal of the Electron Devices Society</i> , 2020 , 8, 448-456	2.3	17
164	Roadmap toward the 10 ps time-of-flight PET challenge. <i>Physics in Medicine and Biology</i> , 2020 , 65, 21RM	19.18	63
163	2020,		8
162	Characterization and Modeling of Mismatch in Cryo-CMOS. <i>IEEE Journal of the Electron Devices Society</i> , 2020 , 8, 263-273	2.3	15
161	A Wideband Low-Power Cryogenic CMOS Circulator for Quantum Applications. <i>IEEE Journal of Solid-State Circuits</i> , 2020 , 55, 1224-1238	5.5	12
160	Wide-field time-gated SPAD imager for phasor-based FLIM applications. <i>Methods and Applications in Fluorescence</i> , 2020 , 8, 024002	3.1	18
159	Cryo-CMOS for Analog/Mixed-Signal Circuits and Systems 2020 ,		5
158	19.1 A Scalable Cryo-CMOS 2-to-20GHz Digitally Intensive Controller for 4B2 Frequency Multiplexed Spin Qubits/Transmons in 22nm FinFET Technology for Quantum Computers 2020 ,		19
157	Cryo-CMOS Interfaces for Large-Scale Quantum Computers 2020 ,		2
156	Quanta burst photography. ACM Transactions on Graphics, 2020, 39,	7.6	21
155	Image reconstruction for novel time domain near infrared optical tomography: towards clinical applications. <i>Biomedical Optics Express</i> , 2020 , 11, 4723-4734	3.5	5
154	Dynamic time domain near-infrared optical tomography based on a SPAD camera. <i>Biomedical Optics Express</i> , 2020 , 11, 5470-5477	3.5	5
153	Multimodal imaging combining time-domain near-infrared optical tomography and continuous-wave fluorescence molecular tomography. <i>Optics Express</i> , 2020 , 28, 9860-9874	3.3	5
152	High fill-factor miniaturized SPAD arrays with a guard-ring-sharing technique. <i>Optics Express</i> , 2020 , 28, 13068-13080	3.3	14
151	Megapixel time-gated SPAD image sensor for 2D and 3D imaging applications. <i>Optica</i> , 2020 , 7, 346	8.6	89

(2019-2020)

150	Quantum Transport in 40-nm MOSFETs at Deep-Cryogenic Temperatures. <i>IEEE Electron Device Letters</i> , 2020 , 1-1	4.4	9
149	Cryogenic-CMOS for Quantum Computing. <i>The Frontiers Collection</i> , 2020 , 501-525	0.3	O
148	Time-Resolved NIROT @ioneer System for Imaging Oxygenation of the Preterm Brain: Preliminary Results. <i>Advances in Experimental Medicine and Biology</i> , 2020 , 1232, 347-354	3.6	O
147	A Cryogenic CMOS Parametric Amplifier. <i>IEEE Solid-State Circuits Letters</i> , 2020 , 3, 5-8	2	6
146	Single-Photon, Time-Gated, Phasor-Based Fluorescence Lifetime Imaging through Highly Scattering Medium. <i>ACS Photonics</i> , 2020 , 7, 68-79	6.3	7
145	A 10-to-12 GHz 5 mW Charge-Sampling PLL Achieving 50 fsec RMS Jitter, -258.9 dB FOM and -65 dBc Reference Spur 2020 ,		7
144	A Scalable Cryo-CMOS Controller for the Wideband Frequency-Multiplexed Control of Spin Qubits and Transmons. <i>IEEE Journal of Solid-State Circuits</i> , 2020 , 55, 2930-2946	5.5	16
143	Subthreshold Mismatch in Nanometer CMOS at Cryogenic Temperatures. <i>IEEE Journal of the Electron Devices Society</i> , 2020 , 8, 797-806	2.3	8
142	Fluorescence lifetime imaging with a megapixel SPAD camera and neural network lifetime estimation. <i>Scientific Reports</i> , 2020 , 10, 20986	4.9	18
141	Toward the Super Temporal Resolution Image Sensor with a Germanium Photodiode for Visible Light. <i>Sensors</i> , 2020 , 20,	3.8	3
140	Designing a DDS-Based SoC for High-Fidelity Multi-Qubit Control. <i>IEEE Transactions on Circuits and Systems I: Regular Papers</i> , 2020 , 67, 5380-5393	3.9	8
139	A Cryo-CMOS Digital Cell Library for Quantum Computing Applications. <i>IEEE Solid-State Circuits Letters</i> , 2020 , 3, 310-313	2	5
138	Introduction to the Special Issue on the 2020 IEEE International Solid-State Circuits Conference (ISSCC). <i>IEEE Journal of Solid-State Circuits</i> , 2020 , 55, 2847-2848	5.5	
137	Time Domain NIRS Optode based on Null/Small Source-Detector Distance for Wearable Applications 2019 ,		4
136	Single-photon avalanche diode imagers in biophotonics: review and outlook. <i>Light: Science and Applications</i> , 2019 , 8, 87	16.7	111
135	. IEEE Journal of Selected Topics in Quantum Electronics, 2019 , 25, 1-6	3.8	6
134	Light-In-Flight Imaging by a Silicon Image Sensor: Toward the Theoretical Highest Frame Rate. <i>Sensors</i> , 2019 , 19,	3.8	11
133	Toward a Full-Flexible and Fast-Prototyping TOF-PET Block Detector Based on TDC-on-FPGA. <i>IEEE Transactions on Radiation and Plasma Medical Sciences</i> , 2019 , 3, 538-548	4.2	13

132	Impact of Classical Control Electronics on Qubit Fidelity. Physical Review Applied, 2019, 12,	4.3	21
131	. IEEE Journal of Solid-State Circuits, 2019 , 54, 3203-3214	5.5	36
130	Phasor-based widefield FLIM using a gated 512B12 single-photon SPAD imager. <i>Proceedings of SPIE</i> , 2019 , 10882,	1.7	5
129	Fluorescence lifetime imaging with a single-photon SPAD array using long overlapping gates: an experimental and theoretical study. <i>Proceedings of SPIE</i> , 2019 , 10882,	1.7	2
128	Optical-stack optimization for improved SPAD photon detection efficiency 2019,		5
127	Quantum correlation measurement with single photon avalanche diode arrays. <i>Optics Express</i> , 2019 , 27, 32863-32882	3.3	20
126	The electronic interface for quantum processors. <i>Microprocessors and Microsystems</i> , 2019 , 66, 90-101	2.4	20
125	Voltage References for the Ultra-Wide Temperature Range from 4.2K to 300K in 40-nm CMOS 2019 ,		7
124	Modeling and Analysis of a Direct Time-of-Flight Sensor Architecture for LiDAR Applications. <i>Sensors</i> , 2019 , 19,	3.8	16
123	Cryo-CMOS Electronics for Quantum Computing Applications 2019,		1
123	Cryo-CMOS Electronics for Quantum Computing Applications 2019, . IEEE Journal of Solid-State Circuits, 2019, 54, 1137-1151	5.5	87
		5.5	
122	. IEEE Journal of Solid-State Circuits, 2019, 54, 1137-1151 A 512B12 SPAD Image Sensor with Integrated Gating for Widefield FLIM. IEEE Journal of Selected		87
122	. IEEE Journal of Solid-State Circuits, 2019, 54, 1137-1151 A 512B12 SPAD Image Sensor with Integrated Gating for Widefield FLIM. IEEE Journal of Selected Topics in Quantum Electronics, 2019, 25, Characterization and Compact Modeling of Nanometer CMOS Transistors at Deep-Cryogenic	3.8	8 ₇
122 121 120	. IEEE Journal of Solid-State Circuits, 2019, 54, 1137-1151 A 512B12 SPAD Image Sensor with Integrated Gating for Widefield FLIM. IEEE Journal of Selected Topics in Quantum Electronics, 2019, 25, Characterization and Compact Modeling of Nanometer CMOS Transistors at Deep-Cryogenic Temperatures. IEEE Journal of the Electron Devices Society, 2018, 6, 996-1006 The Cryogenic Temperature Behavior of Bipolar, MOS, and DTMOS Transistors in Standard CMOS.	3.8	8 ₇ 6 ₂ 7 ²
122 121 120	. IEEE Journal of Solid-State Circuits, 2019, 54, 1137-1151 A 512B12 SPAD Image Sensor with Integrated Gating for Widefield FLIM. IEEE Journal of Selected Topics in Quantum Electronics, 2019, 25, Characterization and Compact Modeling of Nanometer CMOS Transistors at Deep-Cryogenic Temperatures. IEEE Journal of the Electron Devices Society, 2018, 6, 996-1006 The Cryogenic Temperature Behavior of Bipolar, MOS, and DTMOS Transistors in Standard CMOS. IEEE Journal of the Electron Devices Society, 2018, 6, 263-270 Design techniques for a stable operation of cryogenic field-programmable gate arrays. Review of	2.3 2.3	87 62 72
122 121 120 119	. IEEE Journal of Solid-State Circuits, 2019, 54, 1137-1151 A 512B12 SPAD Image Sensor with Integrated Gating for Widefield FLIM. IEEE Journal of Selected Topics in Quantum Electronics, 2019, 25, Characterization and Compact Modeling of Nanometer CMOS Transistors at Deep-Cryogenic Temperatures. IEEE Journal of the Electron Devices Society, 2018, 6, 996-1006 The Cryogenic Temperature Behavior of Bipolar, MOS, and DTMOS Transistors in Standard CMOS. IEEE Journal of the Electron Devices Society, 2018, 6, 263-270 Design techniques for a stable operation of cryogenic field-programmable gate arrays. Review of Scientific Instruments, 2018, 89, 014703 A 256D56 45/65nm 3D-stacked SPAD-based direct TOF image sensor for LiDAR applications with	2.3 2.3	87 62 72 19

114	A co-design methodology for scalable quantum processors and their classical electronic interface 2018 ,		6
113	Cryogenic low-dropout voltage regulators for stable low-temperature electronics. <i>Cryogenics</i> , 2018 , 95, 11-17	1.8	6
112	Dynamic range extension for photon counting arrays. <i>Optics Express</i> , 2018 , 26, 22234-22248	3.3	28
111	Multipurpose, Fully Integrated 128 \$times\$ 128 Event-Driven MD-SiPM With 512 16-Bit TDCs With 45-ps LSB and 20-ns Gating in 40-nm CMOS Technology. <i>IEEE Solid-State Circuits Letters</i> , 2018 , 1, 241-24	14 ²	4
110	A CMOS SPAD Imager with Collision Detection and 128 Dynamically Reallocating TDCs for Single-Photon Counting and 3D Time-of-Flight Imaging. <i>Sensors</i> , 2018 , 18,	3.8	25
109	3D-Stacked CMOS SPAD Image Sensors: Technology and Applications 2018 ,		10
108	Characterization and Model Validation of Mismatch in Nanometer CMOS at Cryogenic Temperatures 2018 ,		18
107	Deep-Cryogenic Voltage References in 40-nm CMOS. <i>IEEE Solid-State Circuits Letters</i> , 2018 , 1, 110-113	2	18
106	Mutually Coupled Time-to-Digital Converters (TDCs) for Direct Time-of-Flight (dTOF) Image Sensors. <i>Sensors</i> , 2018 , 18,	3.8	11
105	A Sensor Network Architecture for Digital SiPM-Based PET Systems. <i>IEEE Transactions on Radiation and Plasma Medical Sciences</i> , 2018 , 2, 574-587	4.2	2
104	Progress in single-photon avalanche diode image sensors in standard CMOS: From two-dimensional monolithic to three-dimensional-stacked technology. <i>Japanese Journal of Applied Physics</i> , 2018 , 57, 100	2 ¹ A ⁴ 3	16
103	Monolithic SPAD Arrays for High-Performance, Time-Resolved Single-Photon Imaging 2018 ,		5
102	High-Performance Back-Illuminated Three-Dimensional Stacked Single-Photon Avalanche Diode Implemented in 45-nm CMOS Technology. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2018 , 24, 1-9	3.8	28
101	Widefield High Frame Rate Single-Photon SPAD Imagers for SPIM-FCS. <i>Biophysical Journal</i> , 2018 , 114, 2455-2464	2.9	12
100	A reconfigurable cryogenic platform for the classical control of quantum processors. <i>Review of Scientific Instruments</i> , 2017 , 88, 045103	1.7	43
99	SPAD imagers for super resolution localization microscopy enable analysis of fast fluorophore blinking. <i>Scientific Reports</i> , 2017 , 7, 44108	4.9	22
98	A High-PDE, Backside-Illuminated SPAD in 65/40-nm 3D IC CMOS Pixel With Cascoded Passive Quenching and Active Recharge. <i>IEEE Electron Device Letters</i> , 2017 , 38, 1547-1550	4.4	42
97	Towards a fully digital state-of-the-art analog SiPM 2017 ,		4

96	Quantum information density scaling and qubit operation time constraints of CMOS silicon-based quantum computer architectures. <i>Npj Quantum Information</i> , 2017 , 3,	8.6	26
95	From the Quantum Moore@Law toward Silicon Based Universal Quantum Computing 2017 ,		3
94	Performance characterization of Altera and Xilinx 28 nm FPGAs at cryogenic temperatures 2017,		4
93	LinoSPAD: A Compact Linear SPAD Camera System with 64 FPGA-Based TDC Modules for Versatile 50 ps Resolution Time-Resolved Imaging. <i>Instruments</i> , 2017 , 1, 6	1.2	16
92	Nonuniformity Analysis of a 65-kpixel CMOS SPAD Imager. <i>IEEE Transactions on Electron Devices</i> , 2016 , 63, 57-64	2.9	31
91	Flexible ultrathin-body single-photon avalanche diode sensors and CMOS integration. <i>Optics Express</i> , 2016 , 24, 3734-48	3.3	6
90	A Cryogenic 1 GSa/s, Soft-Core FPGA ADC for Quantum Computing Applications. <i>IEEE Transactions on Circuits and Systems I: Regular Papers</i> , 2016 , 63, 1854-1865	3.9	19
89	An order-statistics-inspired, fully-digital readout approach for analog SiPM arrays 2016,		5
88	Compact solid-state CMOS single-photon detector array for in vivo NIR fluorescence lifetime oncology measurements. <i>Biomedical Optics Express</i> , 2016 , 7, 1797-814	3.5	20
87	Advances in digital SiPMs and their application in biomedical imaging. <i>Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment</i> , 2016 , 809, 31-52	1.2	66
86	. IEEE Transactions on Electron Devices, 2016 , 63, 65-71	2.9	38
85	Single Photon Counting UV Solar-Blind Detectors Using Silicon and III-Nitride Materials. <i>Sensors</i> , 2016 , 16,	3.8	26
84	Photon-Counting Arrays for Time-Resolved Imaging. Sensors, 2016, 16,	3.8	18
83	Cryo-CMOS for quantum computing 2016 ,		75
82	Characterization of bipolar transistors for cryogenic temperature sensors in standard CMOS 2016,		4
81	Time estimation with multichannel digital silicon photomultipliers. <i>Physics in Medicine and Biology</i> , 2015 , 60, 2435-52	3.8	20
80	11.4 A 67,392-SPAD PVTB-compensated multi-channel digital SiPM with 432 column-parallel 48ps 17b TDCs for endoscopic time-of-flight PET 2015 ,		21
79	. IEEE Journal of Solid-State Circuits, 2015 , 50, 2406-2418	5.5	63

(2014-2015)

78	A first single-photon avalanche diode fabricated in standard SOI CMOS technology with a full characterization of the device. <i>Optics Express</i> , 2015 , 23, 13200-9	3.3	36	
77	Fundamentals of a scalable network in SPADnet-based PET systems 2015,		3	
76	CMOS SPAD Based on Photo-Carrier Diffusion Achieving PDP >40% From 440 to 580 nm at 4 V Excess Bias. <i>IEEE Photonics Technology Letters</i> , 2015 , 27, 2445-2448	2.2	17	
75	Fluorescence lifetime imaging to differentiate bound from unbound ICG-cRGD bothin vitroandin vivo 2015 ,		4	
74	A 1024\$,times,\$ 8, 700-ps Time-Gated SPAD Line Sensor for Planetary Surface Exploration With Laser Raman Spectroscopy and LIBS. <i>IEEE Journal of Solid-State Circuits</i> , 2014 , 49, 179-189	5.5	72	
73	Single-Photon Avalanche Diode Imagers Applied to Near-Infrared Imaging. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2014 , 20, 291-298	3.8	14	
72	Single-photon imaging in complementary metal oxide semiconductor processes. <i>Philosophical Transactions Series A, Mathematical, Physical, and Engineering Sciences</i> , 2014 , 372, 20130100	3	83	
71	A Substrate Isolated CMOS SPAD Enabling Wide Spectral Response and Low Electrical Crosstalk. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2014 , 20, 299-305	3.8	39	
70	A Flexible Ultrathin-Body Single-Photon Avalanche Diode With Dual-Side Illumination. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2014 , 20, 276-283	3.8	5	
69	. IEEE Transactions on Nuclear Science, 2014 , 61, 44-52	1.7	17	
68	SPADnet: Embedded coincidence in a smart sensor network for PET applications. <i>Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment</i> , 2014 , 734, 122-126	1.2	17	
67	SPADnet network modeling, simulation and emulation 2014 ,		2	
66	UV-Sensitive Low Dark-Count PureB Single-Photon Avalanche Diode. <i>IEEE Transactions on Electron Devices</i> , 2014 , 61, 3768-3774	2.9	22	
65	A 65k pixel, 150k frames-per-second camera with global gating and micro-lenses suitable for fluorescence lifetime imaging. <i>Proceedings of SPIE</i> , 2014 , 9141,	1.7	6	
64	Distributed coincidence detection for multi-ring based PET systems 2014,		3	
63	Timing optimization utilizing order statistics and multichannel digital silicon photomultipliers. <i>Optics Letters</i> , 2014 , 39, 552-4	3	9	
62	Architecture and applications of a high resolution gated SPAD image sensor. <i>Optics Express</i> , 2014 , 22, 17573-89	3.3	73	
61	Measurement and modeling of microlenses fabricated on single-photon avalanche diode arrays for fill factor recovery. <i>Optics Express</i> , 2014 , 22, 4202-13	3.3	58	

60	(Invited) Fabrication of Pure-GaB Ge-on-Si Photodiodes for Well-Controlled 100-pA-Level Dark Currents. <i>ECS Transactions</i> , 2014 , 64, 737-745	1	2
59	A Preliminary Study on the Environmental Dependences of Avalanche Propagation in Silicon. <i>IEEE Transactions on Electron Devices</i> , 2013 , 60, 1028-1033	2.9	
58	A 19.6 ps, FPGA-Based TDC With Multiple Channels for Open Source Applications. <i>IEEE Transactions on Nuclear Science</i> , 2013 , 60, 2203-2208	1.7	48
57	The performance of 2D array detectors for light sheet based fluorescence correlation spectroscopy. <i>Optics Express</i> , 2013 , 21, 8652-68	3.3	54
56	Timing optimization of a H-tree based digital silicon photomultiplier. <i>Journal of Instrumentation</i> , 2013 , 8, P09016-P09016	1	13
55	First characterization of the SPADnet sensor: a digital silicon photomultiplier for PET applications. <i>Journal of Instrumentation</i> , 2013 , 8, C12026-C12026	1	7
54	Toward one Giga frames per secondevolution of in situ storage image sensors. Sensors, 2013, 13, 4640)- 5 .8	39
53	The Tipsy single soft photon detector and the Trixy ultrafast tracking detector. <i>Journal of Instrumentation</i> , 2013 , 8, C01036-C01036	1	2
52	A 3.3-to-25V all-digital charge pump based system with temperature and load compensation for avalanche photodiode cameras with fixed sensitivity. <i>Journal of Instrumentation</i> , 2013 , 8, P03013-P0307	13	3
51	EndoTOFPET-US: a novel multimodal tool for endoscopy and positron emission tomography. <i>Journal of Instrumentation</i> , 2013 , 8, C04002-C04002	1	20
50	A 4 🛮 🗗 🖺 16 digital SiPM array with 192 TDCs for multiple high-resolution timestamp acquisition. <i>Journal of Instrumentation</i> , 2013 , 8, P05024-P05024	1	27
49	An Electric Field Volume Integral Equation Approach to Simulate Surface Plasmon Polaritons. <i>Advanced Electromagnetics</i> , 2013 , 2, 15	1.2	2
48	. IEEE Journal of Solid-State Circuits, 2012 , 47, 1394-1407	5.5	111
47	Fluorescent magnetic bead and cell differentiation/counting using a CMOS SPAD matrix. <i>Sensors and Actuators B: Chemical</i> , 2012 , 174, 609-615	8.5	13
46	. IEEE Transactions on Circuits and Systems I: Regular Papers, 2012 , 59, 604-615	3.9	1
45	A fully-integrated 780 B 00fh2 multi-digital silicon photomultiplier with column-parallel time-to-digital converter 2012 ,		3
44	A 128-Channel, 8.9-ps LSB, Column-Parallel Two-Stage TDC Based on Time Difference Amplification for Time-Resolved Imaging. <i>IEEE Transactions on Nuclear Science</i> , 2012 , 59, 2463-2470	1.7	46
43	A wide spectral range single-photon avalanche diode fabricated in an advanced 180 nm CMOS technology. <i>Optics Express</i> , 2012 , 20, 5849-57	3.3	56

42	FPGA implementation of a 32x32 autocorrelator array for analysis of fast image series. <i>Optics Express</i> , 2012 , 20, 17767-82		30
41	Sensor network architecture for a fully digital and scalable SPAD based PET system 2012 ,		8
40	Multi-channel digital SiPMs: Concept, analysis and implementation 2012,		27
39	A Handheld Intra-Operative ⊞ Sensing System. <i>Procedia Engineering</i> , 2011 , 25, 988-991		
38	A 128-channel, 9ps column-parallel two-stage TDC based on time difference amplification for time-resolved imaging 2011 ,		13
37	Fast single-photon avalanche diode arrays for laser Raman spectroscopy. <i>Optics Letters</i> , 2011 , 36, 3672-45		36
36	Hybrid polymer microlens arrays with high numerical apertures fabricated using simple ink-jet printing technique. <i>Optical Materials Express</i> , 2011 , 1, 259		74
35	A 1601128 single-photon image sensor with on-pixel 55ps 10b time-to-digital converter 2011 ,		47
34	An implementation of a spike-response model with escape noise using an avalanche diode. <i>IEEE Transactions on Biomedical Circuits and Systems</i> , 2011 , 5, 231-43		3
33	Reduction of Fixed-Position Noise in Position-Sensitive Single-Photon Avalanche Diodes. <i>IEEE Transactions on Electron Devices</i> , 2011 , 58, 2354-2361		12
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